

BYT5AQGP

**SINTERED GLASS JUNCTION
FAST SWITCHING PLASTIC RECTIFIER**
VOLTAGE: 1200V CURRENT: 5.0A

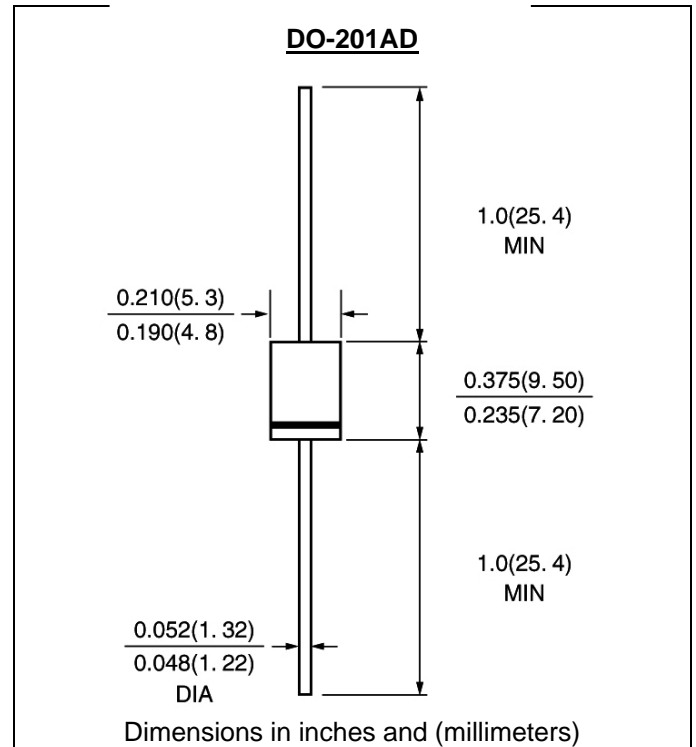


FEATURE

High temperature metallurgically bonded construction
Sintered glass cavity free junction
Capability of meeting environmental standard of MIL-S-19500
High temperature soldering guaranteed
350°C /10sec/0.375"lead length at 5 lbs tension
Operate at Ta =55°C with no thermal run away
Typical Ir<0.1μA

MECHANICAL DATA

Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
Polarity: color band denotes cathode
Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	BYT5AQGP	units
Maximum Recurrent Peak Reverse Voltage	V _{rrm}	1200	V
Maximum RMS Voltage	V _{rms}	840	V
Maximum DC blocking Voltage	V _{dc}	1200	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta =55°C	I _{f(av)}	5.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{fsm}	125	A
Maximum Forward Voltage at rated Forward Current and 25°C	V _f	1.8	V
non-repetitive reverse avalanche energy I _{(BR)R} =0.4A	E _r	10	mJ
Maximum full load reverse current full cycle average at 55°C Ambient	I _{r(av)}	100	μA
Maximum DC Reverse Current Ta =25°C at rated DC blocking voltage Ta =150°C	I _r	5.0 100	μA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	100	nS
Typical Junction Capacitance (Note 2)	C _j	60	pF
Typical Thermal Resistance (Note 3)	R _{th(ja)}	20	°C/W
Storage and Operating Junction Temperature	T _{stg} , T _j	-65 to +175	°C

Note: 1.Reverse Recovery Condition I_f =0.5A, I_r =1.0A, I_{rr} =0.25A
2.Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3.Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

RATINGS AND CHARACTERISTIC CURVES BYT5AQP

